

## CHENMKO ENTERPRISE CO.,LTD

### SURFACE MOUNT

VICES SCHOTTKY BARRIER RECTIFIER

VOLTAGE RANGE 20 - 40 Volts CURRENT 1.0 Ampere

SSM5819SPT

SSM5817SPT

**THRU** 

**FEATURES** 

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- \* For surface mounted applications
- \* Low profile package
- \* Built-in strain relief
- \* Metal silicon junction, majority carrier conduction
- \* Low power loss, high efficiency
- \* High current capability, low forward voltage drop
- High surge capability
- \* For use in low voltage high frequency inverters, free wheeling, and polarity protection applications
- \* High temperature soldering guaranteed : 260°C/10 seconds at terminals
- \* Lead free devices

### **MECHANICAL DATA**

Case: JEDEC SOD-123 molded plastic

Terminals: Solder plated, solderable per MIL-STD-750,

Method 2026

Polarity: Color band denotes cathode end

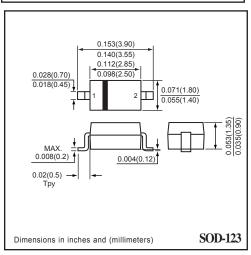
Weight: 0.001 ounce 0.032 gram

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at  $25^{\circ}\text{C}$  ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

# SOD-123



### **MAXIMUM RATINGES** ( At $TA = 25^{\circ}C$ unless otherwise noted )

RATINGS	SYMBOL	SSM5817SPT	SSM5818SPT	SSM5819SPT	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	20	30	40	Volts
Maximum RMS Voltage	VRMS	14	21	28	Volts
Maximum DC Blocking Voltage	VDC	20	30	40	Volts
Maximum Average Forward Rectified Current at TL = 90°C	lo	1.0			Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method) $TL = 70^{\circ}C$	IFSM	25			Amps
Typical Junction Capacitance (Note 2)	Cı	110			pF
Typical Thermal Resistance (Note 1)	R θ JL	80			
Storage and Operating Temperature Range	TJ, TSTG	-65 to +125			

### **ELECTRICAL CHARACTERISTICS** ( At TA = $25^{\circ}$ C unless otherwise noted )

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CHARACTERISTICS		SYMBOL	SSM5817SPT	SSM5818SPT	SSM5819SPT	UNITS
Maximum Instantaneous Forward Voltage at 1.0 A DC		VF	0.45	0.55	0.60	Volts
Maximum Average Reverse Current	@ Ta = 25°C	lr.		1.0		mAmps
at Rated DC Blocking Voltage	@ TA = 100°C	l IK	10			

NOTES: 1. Thermal Resistance ( Junction to Lead ): PC Board Mounted on 0.2 X 0.2" ( 5 X 5mm ) copper pad area.

2. Measured at 1.0 MHz and applied reverse voltage of 4.0 volts

3. ESD sensitive product handling required.

2002-9

#### RATING CHARACTERISTIC CURVES (SSM5817SPT THRU SSM5819SPT) FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE FIG. 2 - TYPICAL INSTANTANEOUS FORWARD INSTANTANEOUS FORWARD CURRENT, (A) CHARCTERISTICS 20 AVERAGE FORWARD CURRENT, (A) SSM5817 10 .75 .50 1.0 Single Half Wave 60Hz .25 TJ =25 Resistive or Inductive Load Pulse Width = 300us 1% Duty Cycle 0 0.1 0 20 40 60 120 140 .3 1.1 1.3 LEAD TEMPERATURE, (°C) INSTANTANEOUS FORWARD VOLTAGE, (V) FIG. 3 - TYPICAL REVERSE CHARACTERISTICS FIG. 4 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT 100 30 INSTANTANEOUS REVERSE CURRENT, (mA) PEAK FORWARD SURGE CURRENT, (A) 25 10 8.3 ms Single Half Sine-Wa (JEDEC Method) 20 1.0 15 .10 10 .01 5 .001 0 2 20 50 100 20 80 100 120 140 5 10 PERCENT OF RATED PEAK REVERSE VOLTAGE, (%) NUMBER OF CYCLES AT 60Hz FIG. 5 - TYPICAL JUNCTION CAPACITANCE 400 JUNCTION CAPACITANCE, (pF) 200 100 60 40 20 10 40 REVERSE VOLTAGE, (V)